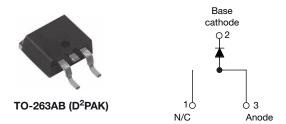


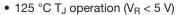
High Performance Schottky Rectifier, 20 A



PRODUCT SUMMARY	PRODUCT SUMMARY					
I _{F(AV)}	20 A					
V_{R}	15 V					
V _F at I _F	0.33 V					
I _{RM} max.	600 mA at 100 °C					
T _J max.	125 °C					
E _{AS}	10 mJ					
Package	TO-263AB (D ² PAK)					
Diode variation	Single die					

FEATURES

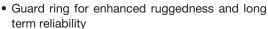
High

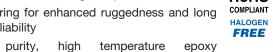


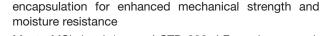












- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	20	Α				
V _{RRM}		15	V				
I _{FSM}	t _p = 5 μs sine	700	A				
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V				
T _J	Range	-55 to +125	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20L15TSPbF	UNITS			
Maximum DC reverse voltage	V _R	T _{.l} = 100 °C	15	V			
Maximum working peak reverse voltage	V_{RWM}	1j = 100 C	15	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	DL TEST CONDITIONS VALUES					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C, rectangular waveform		20			
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	700	Α		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 6 \text{mH}$		10	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim		2	А		



ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS TYP. MA				
		19 A	T _{.1} = 25 °C	-	0.41		
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 C	-	0.52	V	
See fig. 1	V _{FM} (1)	19 A	T _J = 125 °C	0.25	0.33		
		40 A		0.37	0.50		
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	-	10	mA	
See fig. 2	IRM (")	T _J = 100 °C	v _R = nateu v _R	-	600	ША	
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum		0.1	82	V	
Forward slope resistance	r _t	rj = rj maximum		7.	.6	mΩ	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} , (test signal ran	ge 100 kHz to 1 MHz), 25 °C	-	2000	pF	
Typical series inductance	L _S	Measured lead to lead 5 m	m from package body	8	-	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs	

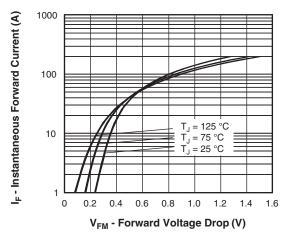
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	T _J		-55 to +125	°C	
Maximum storage temperature range	T _{Stg}		-55 to +150	C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (For TO-220)	0.50	°C/W	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	40		
Approximate weight			2	g	
Approximate weight			0.07	OZ.	
Mounting torque		Non-lubricated threads	6 (5)	kgf · cm	
Mounting torque maximum	1	Non-iubricated threads	12 (10)	(lbf · in)	
Marking device		Case style D ² PAK	20L1	5TS	







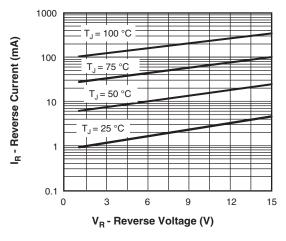


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

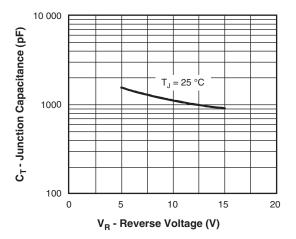


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

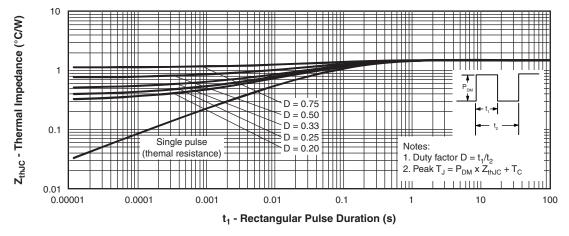


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



Allowable Case Temperature (°C)

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Vishay Semiconductors

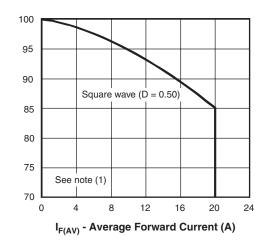


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

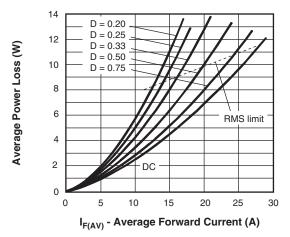


Fig. 6 - Forward Power Loss Characteristics

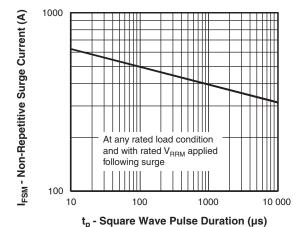


Fig. 7 - Maximum Non-Repetitive Surge Current

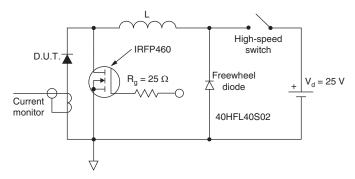


Fig. 8 - Unclamped Inductive Test Circuit

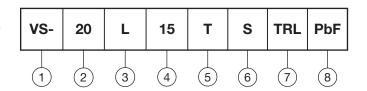
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (20 A)

 $L = Low V_F$

3 Voltage rating (15 = 15 V)

T = Schottky series

 $S = D^2PAK$

• None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 PbF = lead (Pb)-free

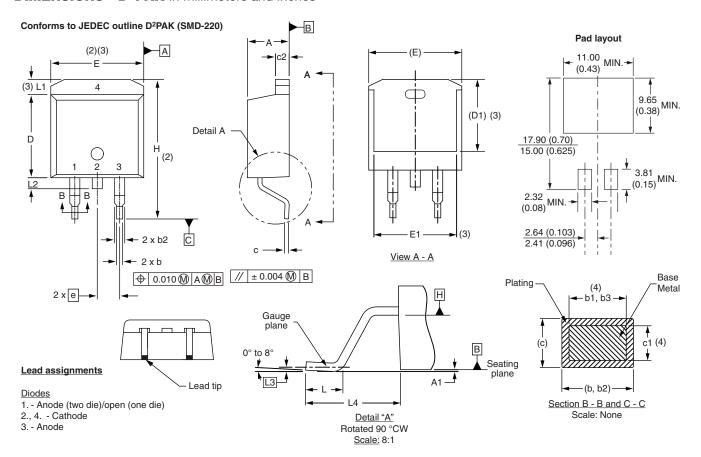
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-20L15TSPbF	50	1000	Antistatic plastic tubes				
VS-20L15TSTRLPbF	800	800	13" diameter reel				
VS-20L15TSTRRPbF	800	800	13" diameter reel				
VS-20L15T-1PbF	50	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95014</u>					
Part marking information <u>www.vishay.com/doc?95008</u>					
Packaging information	www.vishay.com/doc?95032				



D²PAK, TO-262

DIMENSIONS - D²PAK in millimeters and inches



SYMBOL	MILLIN	IETERS	TERS INCHES		
STIMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

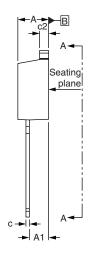
(7) Outline conforms to JEDEC outline TO-263AB

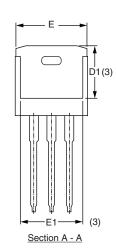
D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches

Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) 1 L2 B B B L (2) 3 x b2 3 x b2 3 x b2





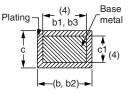
⊕ 0.010 M AM B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	ETERS	INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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